

Single 2-input OR Gate

General Description

The ET74LVC1G32 is a single 2-input OR Gate in three tiny footprint packages. The device performs much as LCX multi-gate products in speed and drive.

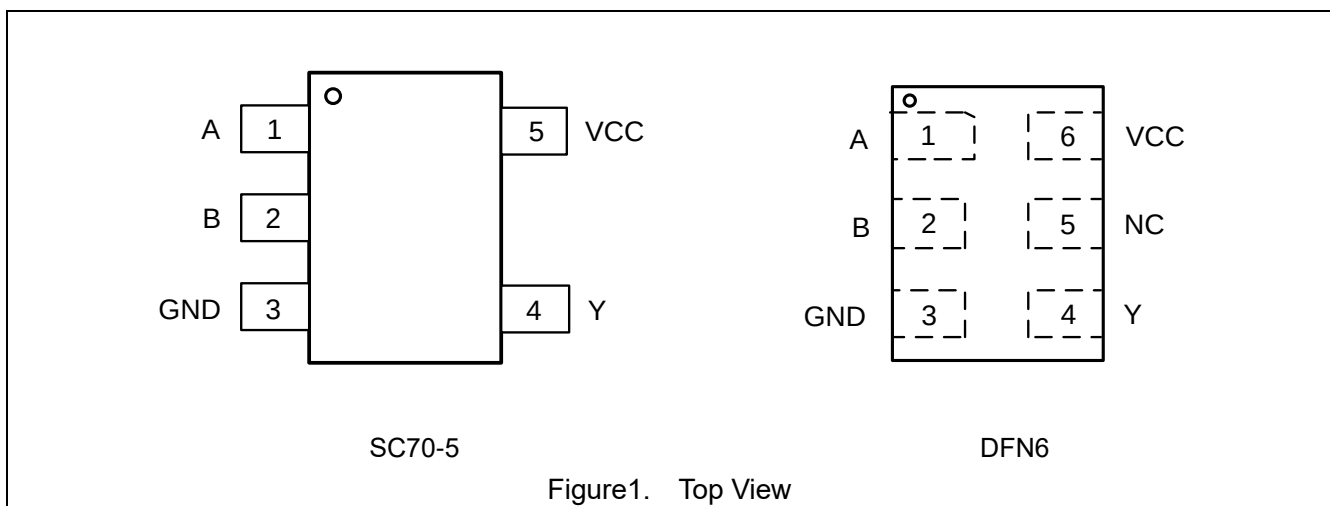
Features

- Designed for 1.65V to 5.5V V_{CC} Operation
- 4.8ns t_{PD} at 5V (typ)
- Source/Sink 24mA at 3.0V
- Over-Voltage Tolerant Inputs
- These Devices are Pb-Free and are RoHS Compliant

Device Information

Part No.	Package	Packing Option	MSL
ET74LVC1G32	SC70-5 (1.3mm×2.1mm)	Tape and Reel, 3K	1
ET74LVC1G32T	SOT23-5 (1.6mm×2.9mm)	Tape and Reel, 3K	3
ET74LVC1G32Y	DFN6 (1.0mm×1.5mm)	Tape and Reel, 3K	1

Pin Configuration



ET74LVC1G32

Pin Function

SC70-5/ SOT23-5

Pin No.	Pin Name	Function
1	A	Input A
2	B	Input B
3	GND	Ground
4	Y	Output Y
5	VCC	Supply Voltage

DFN6

Pin No.	Pin Name	Function
1	A	Input A
2	B	Input B
3	GND	Ground
4	Y	Output Y
5	NC	No Connect
6	VCC	Supply Voltage

Block Diagram

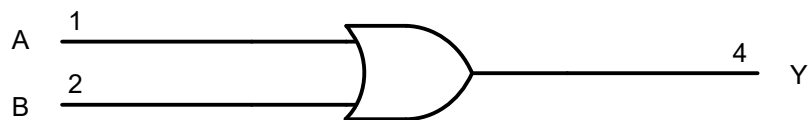


Figure2. Logic Symbol

Functional Description

Function Table

Input		Output
A	B	Y
L	L	L
L	H	H
H	L	H
H	H	H

ET74LVC1G32

Absolute Maximum Ratings

Symbol	Parameter		Value	Unit
V _{CC}	DC Supply Voltage		-0.5 to 7	V
V _I	DC Input Voltage ⁽¹⁾		-0.5 ≤ V _I ≤ +7	V
V _O	DC Output Voltage Output in Higher or Low State		-0.5 to V _{CC} + 0.5	V
I _{IK}	DC Input Diode Current	V _I < GND	-50	mA
I _{OK}	DC Output Diode Current	V _O < GND, V _O > V _{CC}	±50	mA
I _O	DC Output Sink Current		±50	mA
I _{CC}	DC Supply Current per Supply Pin		±100	mA
I _{GND}	DC Ground Current per Supply Pin		±100	mA
T _{STG}	Storage Temperature Range		-65 to 150	°C
T _L	Lead Temperature, Soldering 10 Seconds		260	°C
T _J	Max Junction Temperature		150	°C
V _{ESD}	ESD Classification	Human Body Model ⁽²⁾	±4000	V
		Charged Device Model ⁽³⁾	±1000	
I _{LU}	Latch up Current Above V _{CC} and GND at 125°C ⁽⁴⁾		±100	mA

Stresses exceeding those listed in this table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Note1. IO absolute maximum rating must be observed.

Note2. Tested to EIA/JESD22-A114-A.

Note3. Tested to JESD22-C101-A.

Note4. Tested to EIA/JESD78.

Thermal Characteristics

Symbol	Package	Ratings	Value	Unit
R _{θJA}	SC70-5	Thermal Characteristics, Thermal Resistance, Junction-to-Air	300	°C/W
	SOT23-5		250	
	DFN6		440	
R _{θJB}	SC70-5	Thermal Characteristics, Thermal Resistance, Junction-to-board	75	°C/W
	SOT23-5		65	
	DFN6		270	
P _D	SC70-5	Power Dissipation in Still Air at 85°C	215	mW
	SOT23-5		260	
	DFN6		150	

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Recommended Operating Conditions

Symbol	Parameter		Min	Max	Unit
V _{CC}	DC Supply Voltage Operating		1.65	5.5	V
	Date Retention		1.5	5.5	
V _{IN}	DC Input Voltage		0	5.5	V
V _{OUT}	DC Output Voltage (High or Low State)		0	5.5	V
T _A	Operating Temperature Range		-40	125	°C
t _r ,t _f	Input Rise and Fall Time	V _{CC} = 2.5 V ± 0.2 V	0	20	ns/V
		V _{CC} = 3.0 V ± 0.3 V	0	10	
		V _{CC} = 5.0 V ± 0.5 V	0	5	

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied.

Electrical Characteristics

DC Electrical Characteristics

Symbol	Parameter	Condition	V _{CC} (V)	T _A = 25 °C			-40°C ≤ T _A ≤ 125°C		Unit
				Min	Typ	Max	Min	Max	
V _{IH}	High-Level Input Voltage		1.65to1.95 2.3 to 5.5	0.75V _{CC} 0.7V _{CC}			0.75V _{CC} 0.7V _{CC}		V
V _{IL}	Low-Level Input Voltage		1.65to1.95 2.3 to 5.5			0.25V _{CC} 0.3V _{CC}		0.25V _{CC} 0.3V _{CC}	V
V _{OH}	High-Level Output Voltage	I _{OH} =-100μA	1.65 to 5.5	V _{CC} -0.1	V _{CC}		V _{CC} -0.1		V
		I _{OH} =-3mA	1.65	1.29	1.52		1.29		
		I _{OH} =-8mA	2.3	1.9	2.1		1.9		
		I _{OH} =-12mA	2.7	2.2	2.4		2.2		
		I _{OH} =-16mA	3.0	2.4	2.7		2.4		
		I _{OH} =-24mA	3.0	2.3	2.5		2.3		
		I _{OH} =-32mA	4.5	3.8	4.0		3.8		
V _{OL}	Low-Level Output Voltage	I _{OL} =100μA	1.65 to 5.5		0.0	0.1		0.1	V
		I _{OL} =3mA	1.65		0.08	0.24		0.24	
		I _{OL} =8mA	2.3		0.20	0.3		0.3	
		I _{OL} =12mA	2.7		0.22	0.4		0.4	
		I _{OL} =16mA	3.0		0.28	0.4		0.4	
		I _{OL} =24mA	3.0		0.38	0.55		0.55	
		I _{OL} =32mA	4.5		0.42	0.55		0.55	
I _{IN}	Input Leakage Current	V _{IN} = 5.5 V or GND	0 to 5.5			± 0.1		±1.0	μA

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DC Electrical Characteristics(Continued)

Symbol	Parameter	Condition	V _{CC} (V)	T _A = 25 °C			-40°C ≤ T _A ≤ 125°C		Unit
				Min	Typ	Max	Min	Max	
I _{OFF}	Power Off Leakage Current	V _{IN} = 5.5 V or V _{OUT} = 5.5 V	0			1.0		10	μA
I _{CC}	Quiescent Supply Current	V _{IN} = 5.5 V or GND	5.5			1.0		10	μA

AC Electrical Characteristics

$$t_r = t_f = 3ns$$

Symbol	Parameter	Condition	V _{CC} (V)	T _A = 25 °C			-40°C ≤ T _A ≤ 125°C		Unit
				Min	Typ	Max	Min	Max	
t _{PD}	Propagation Delay (Figure3and4)	R _L = 1MΩ C _L = 15pF	1.65	2.0	10.1	12.9	2.0	13.9	ns
			1.8	2.0	9.1	11.6	2.0	12.4	
		R _L = 1MΩ C _L = 15pF	2.5	0.2	6.0	7.7	0.8	8.2	
		R _L = 1MΩ C _L = 15pF	3.3	0.8	5.0	6.5	0.5	7.0	
				1.2	5.6	7.1	1.5	7.6	
		R _L = 1MΩ C _L = 15pF	5.0	0.5	4.4	5.6	0.5	6.1	
		R _L = 500Ω C _L = 50pF		0.8	4.8	6.1	0.8	6.6	

Capacitance Characteristics

Symbol	Parameter	Condition	Typ	Unit
C _{IN}	Input Capacitance	V _{CC} = 5.5V, V _I = 0V or V _{CC}	2.5	pF
C _{PD}	Power Dissipation Capacitance ⁽⁵⁾	10MHz, V _{CC} = 3.3V, V _I = 0V or V _{CC}	21	pF
		10MHz, V _{CC} = 5.5V, V _I = 0V or V _{CC}	21	

Note5. C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC(OPR)}=C_{PD}×V_{CC}×fin+I_{CC}×C_{PD} is used to determine the no-load dynamic power consumption; P_D=C_{PD}×V_{CC}² ×fin+I_{CC}×V_{CC}×Fig.

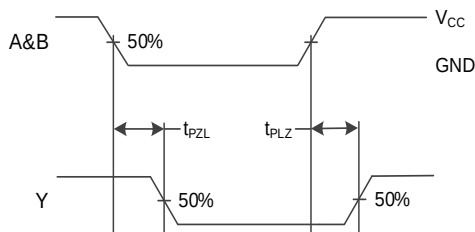


Figure3. Switching Waveform

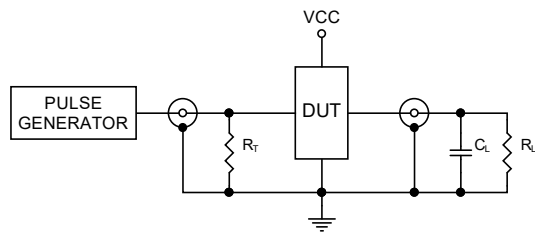
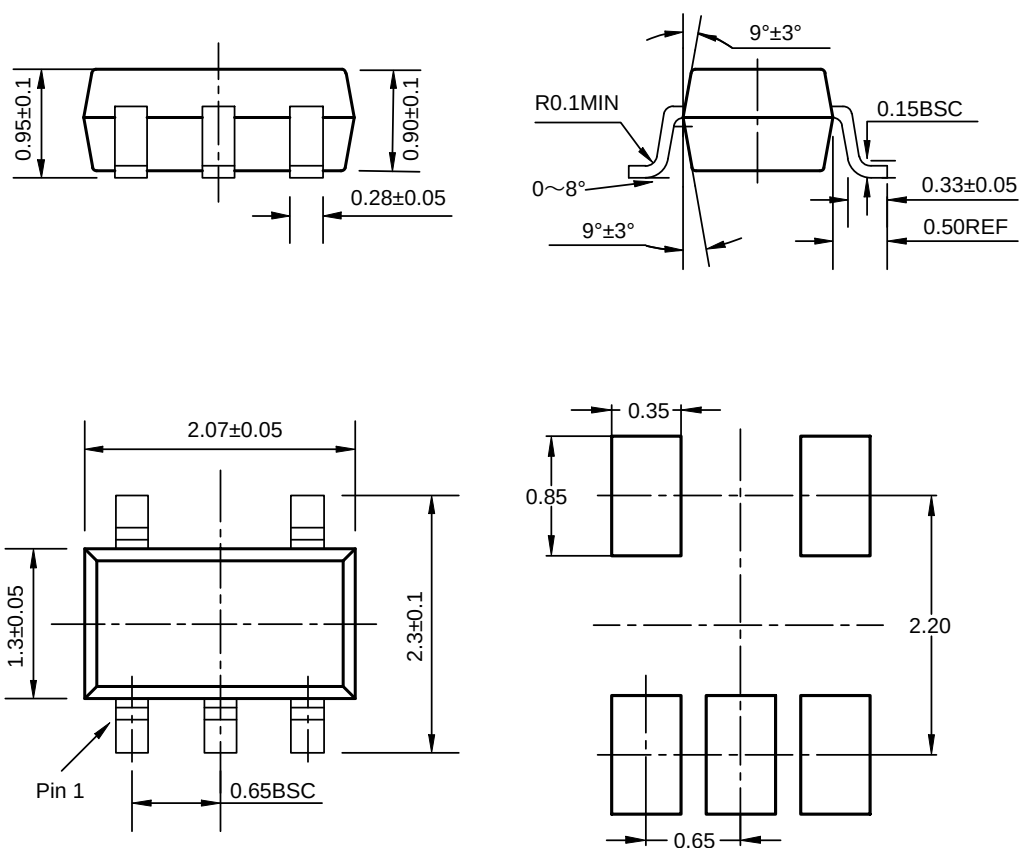


Figure4. Test Circuit

ET74LVC1G32

Package Dimension

SC70-5

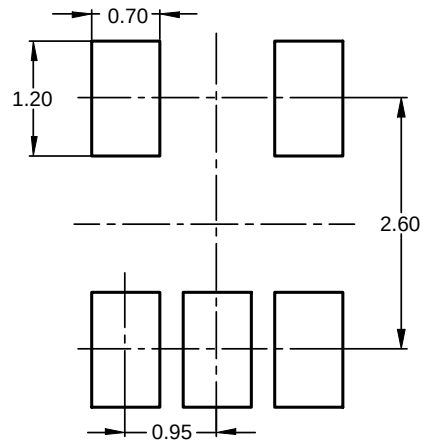
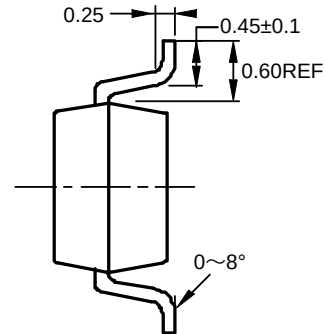
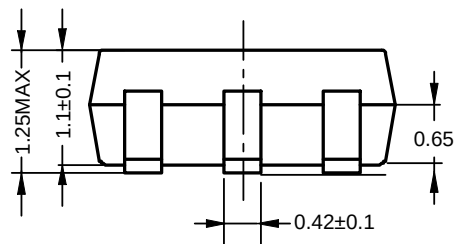
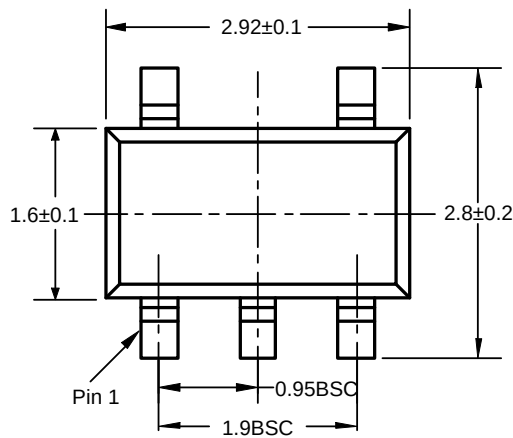


Recommended Land Pattern

Unit: mm

ET74LVC1G32

SOT23-5

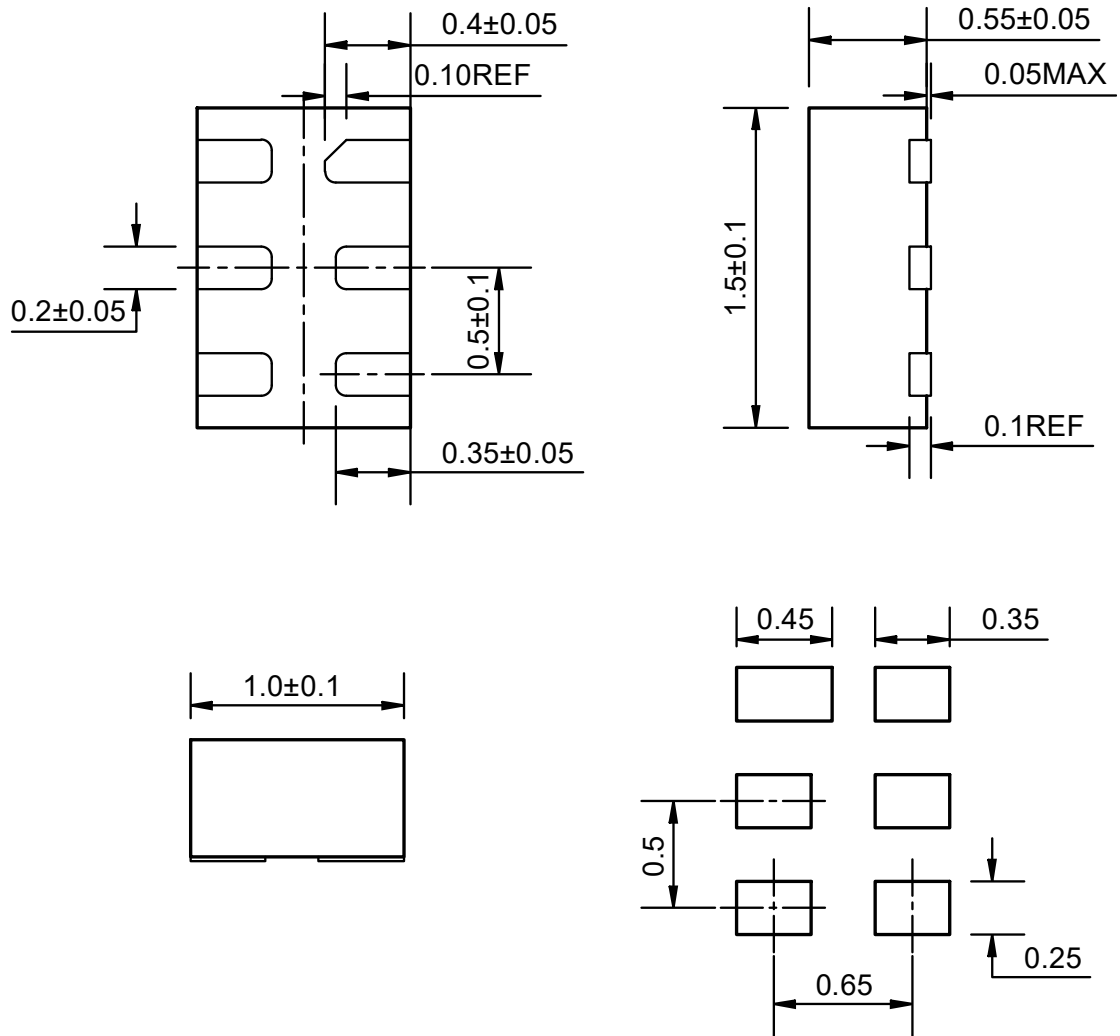


Recommended Land Pattern

Unit: mm

ET74LVC1G32

DFN6 (1.0×1.5)



Recommended Land Pattern

Unit: mm

ET74LVC1G32

Revision History and Checking Table

Version	Date	Revision Item	Modifier	Function & Spec Checking	Package & Tape Checking
1.0	2017-10-23	Original Version	Ma Yong jian	Ma Yong jian	Liu Jia Ying
1.1	2019-07-18	Update AC Table and Device Information	Ma Yong jian	Ma Yong jian	Liu Jia Ying
1.2	2022-06-10	ESD Update	Shibo	Shibo	Zhuji
1.3	2022-07-7	Add $\theta_{JB}, T_A = 125^{\circ}\text{C}$	Shibo	Shibo	Zhuji
1.4	2022-11-11	Update Typeset and Thermal Characteristics	Wuhan	Shibo	Zhuji
1.5	2023-11-29	Update Typeset /ESD	Shibo	Shibo	Liuji
1.6	2025-05-29	Add Packing Option	Yang xiaoxu	Yang xiaoxu	Liu jiaying